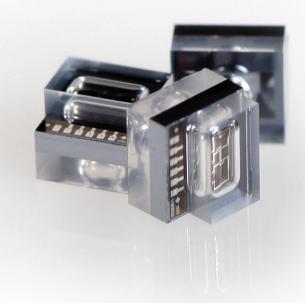


### PRESSURE SENSOR DIE

0 to 1500 kPa (0 to 218 psi)

#### **Features**

- Absolute pressure sensor die
- High reliability and low drift over lifetime
- High media compatibility
- Backside media access
- Wide temperature operating range
- Single side bond pad access



#### Description

The SW414-15 uncompensated piezoresistive pressure sensor die is bulk micromachined and designed for affordable and reliable high pressure measurements in a broad range of industrial applications and designs.

SW414-15 has excellent media compatibility due to the patented triple stack sensor design with buried backside piezoresistive elements. With the backside media access, the piezo resistors will not come in direct contact with the measurement media. The design improves stability and sensor lifetime compared to many traditional sensor designs.

The design and performance of SW414-15 makes it ideal for high accuracy measurements, also in harsh environments. The long term stability is outstanding and has been proven in applications during a period of more than 10 years.

The sensor die can be connected to passive compensation and/or signal conditioning as required for a given application.

All sensor die products are 100% electrically tested and visually inspected.

SW414-15 is offered as bare die and wafer deliveries.

SW414-15 SW414-15W

## sensonor

MECHANICAL DIMENSIONS (in µm)

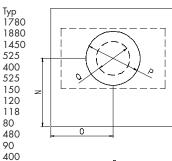
#### **GENERAL CONDITIONS**

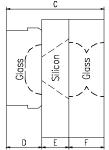
Parameter	Min	Тур	Max	Unit	Comments
Operating supply voltage		5.0		V	
Operating temperature	-40		125	°C	
Operating pressure	0		1500	kPa	Absolute pressure
Overload pressure	3300			kPa	
Breakdown voltage		14		V	At I=5.0μA
Leakage current		0.2		nA	At Vdd=4.0V

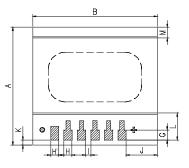
#### FUNCTIONAL CHARACTERISTICS (@25°C,5V)

Parameter	Тур	Unit	
Bridge resistor			
Bridge resistance	3.7	kΩ	
Temp.coeff. bridge resistor (1st order)	1.5	10 <sup>-3</sup> /°C	
Temp.coeff. bridge resistor (2 <sup>nd</sup> order)	9.0	10 <sup>-6</sup> /°C <sup>2</sup>	
Common mode voltage	0.5*Vdd	V	
Sensitivity			
Sensitivity	12	μV/VkPa	
Temp.coeff. sensitivity drift (1st order)	-2.5	10 <sup>-3</sup> /°C	
Non linearity	See separate chart	%FSO	
Zero point			
Zero point	±2.6	mV/V	
Temp.coeff. zero point drift (1st order)	±20	μV/V°C	

# DIM А В C D E F G H H I J K L M N O P

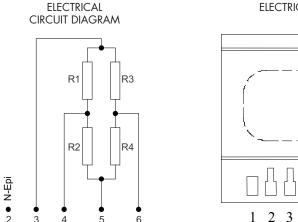






**ELECTRICAL CONTACTS** 

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	Pressure [kPa]						

P-Substrate	N-Epi		R2		R4	
1	2	3	4	5	6	

ORDERING INFORMATION	
Description	Model
10 or 100 dies in waffle packs	SW414-15
Diced wafers on tape	SW415-15W

#### **CONTACT INFORMATION**

Sensonor Technologies AS Phone: +47 3303 5000 - Fax: +47 3303 5005 sales@sensonor.no www.sensonor.com